



#### SINGLE SCHMITT TRIGGER BUFFER

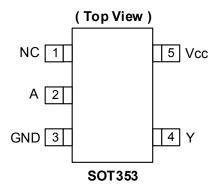
### **Description**

The 74LVC1G17Q is an automotive-compliant, single 1-input Schmitt trigger buffer with a standard push-pull output. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output preventing damaging current backflow when the device is powered down.

The gate performs the positive Boolean function:

$$Y = A$$

### Pin Assignments



### **Features**

- Grade 1 Ambient Temperature Operation: -40°C to 125°C
- Wide Supply Voltage Range from 1.65 to 5.5V
- ±24mA Output Drive at 3.3V
- CMOS Low Power Consumption
- I<sub>OFF</sub> Supports Partial-Power-Down Mode Operation
- Inputs Accept up to 5.5V Regardless of Vcc Level
- ESD Protection Tested per AEC-Q100
- Exceeds 2000V Human Body Model (AEC Q100-002)
- Exceeds 1000V Charged Device Model (AEC Q100-011)
- Latch-Up Exceeds 100mA (AEC Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74LVC1G17Q is suitable for automotive applications requiring specific change control and is AEC-Q100 qualified, has a grade 1 -40°C to 125°C temperature rating, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

### **Applications**

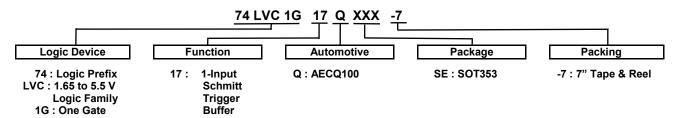
- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide Array of Products such as:
  - Automotive Applications Within Grade 1 Temperature Range
  - Industrial Computing/Controls/Automation
  - High Reliability Networking/Communications
  - Industrial/Agricultural Equipment

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



### **Ordering Information**



Part Number	Package	Package	Package	7" Tape ar	nd Reel
rait Nullibei	Code	(Notes 4 & 5)	Size	Quantity	Part Number Suffix
74LVC1G17QSE-7	SE	SOT353	2.0mm × 2.0mm × 1.1mm 0.65 mm lead pitch	3000/Tape & Reel	-7

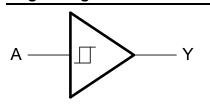
Notes:

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.
5. Pad layout as shown in Diodes Inc. suggested pad layouts, which can be found on our website at see http://www.diodes.com/package-outlines.html.
6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf.

### **Pin Descriptions**

Pin Name	Description
NC	No Connection
Α	Data Input
GND	Ground
Υ	Data Output
Vcc	Supply Voltage

# **Logic Diagram**



### **Function Table**

Inputs	Output
Α	Υ
Н	Н
L	L



### Absolute Maximum Ratings (Notes 7 & 8)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High Impedance or I <sub>OFF</sub> State	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>1</sub> < 0	-50	mA
lok	Output Clamp Current	-50	mA
Io	Continuous Output Current	±50	mA
I <sub>CC,</sub> I <sub>GND</sub>	Continuous Current Through V <sub>CC</sub> or GND	±100	mA
TJ	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes:

# **Recommended Operating Conditions** (Note 9)

Symbol		Parameter	Min	Max	Unit
\/	On a ration at Malta are	Operating	1.65	5.5	V
V <sub>CC</sub>	Operating Voltage	Data retention only	1.5	_	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65V	_	-4	
		V <sub>CC</sub> = 2.3V	_	-8	
I <sub>OH</sub>	High-Level Output Current	V <sub>CC</sub> = 2.7V	_	-12	mA
		V <sub>CC</sub> = 3V	_	-24	
		V <sub>CC</sub> = 4.5V	_	-32	
		V <sub>CC</sub> = 1.65V	_	4	
		V <sub>CC</sub> = 2.3V	_	8	
I <sub>OL</sub>	Low-Level Output Current	V <sub>CC</sub> = 2.7V	_	12	mA
		V <sub>CC</sub> = 3V	_	24	
		V <sub>CC</sub> = 4.5V	_	32	
T <sub>A</sub>	Operating Free-Air Temperature	_	-40	+125	°C

Notes: 9. Unused inputs should be held at  $V_{\mbox{\footnotesize{CC}}}$  or Ground.

<sup>7.</sup> Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

<sup>8.</sup> Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range..



# **Electrical Characteris**tics $T_A = -40$ °C to +125°C (All typical values are at $V_{CC} = 3.3$ V, $T_A = +25$ °C)

Symbol	Parameter	Test Co	nditions	$\mathbf{v}_{ ext{cc}}$	Min	Тур.	Max	Unit		
		_		1.65V	0.79	1	1.16			
		_		2.3V	1.11	_	1.56			
$V_{T^+}$	Positive- Going Input Threshold Voltage	_		3V	1.50	_	1.87	V		
	Threshold Voltage	_		4.5V	2.16	_	2.74			
		_		5.5V	2.61	_	3.33	]		
		_		1.65V	0.39	_	0.64			
		_		2.3V	0.58	_	0.89			
$V_{T-}$	Negative- Going Input	_		3V	0.84	_	1.16	V		
	Threshold Voltage	_		4.5V	1.41	_	1.79	1		
		_		5.5V	1.87	_	2.29	]		
		_		1.65V	0.37	_	0.62			
		_		2.3V	0.48	_	0.77	]		
$\Delta V_{T}$	Hysteresis	_		3V	0.56	_	0.87	V		
	(V <sub>T+</sub> - V <sub>T-</sub> )	_		4.5V	0.71	_	1.04	]		
		_		5.5V	0.71	_	1.11	1		
			I <sub>OH</sub> = -100μA	1.65V to 5.5V	V <sub>CC</sub> - 0.1	_	_			
			I <sub>OH</sub> = -4mA	1.65V	0.95	_	_	1		
	High Level Output Voltage $V_I = V_{T-1}$	., .,	I <sub>OH</sub> = -8mA	2.3V	1.7	_	_	] ,,		
$V_{OH}$		High Level Output Voltage	High Level Output Voltage	High Level Output Voltage Vi	ligh Level Output Voltage $V_1 = V_{T+}$	I <sub>OH</sub> = -12mA	2.7V	1.9	_	_
			I <sub>OH</sub> = -24mA	3V	2.0	_	_	]		
					I <sub>OH</sub> = -32mA	4.5V	3.4	_	_	]
			I <sub>OL</sub> = 100μA	1.65V to 5.5V	_	_	0.1			
			I <sub>OL</sub> = 4mA	1.65V	_	_	0.7	]		
.,		., .,	I <sub>OL</sub> = 8mA	2.3V	_	_	0.45	] ,,		
$V_{OL}$	Low-Level Output Voltage	$V_1 = V_{T}$	I <sub>OL</sub> = 12mA	2.7V	_	_	0.6	V		
			I <sub>OL</sub> = 24mA	3V	_	_	0.8	]		
			I <sub>OL</sub> = 32mA	4.5V	_	_	0.8	]		
II	Input Current	$V_I = 5.5V$ or GND	V <sub>I</sub> = 5.5V or GND	0 to 5.5V	_	_	±1	μΑ		
I <sub>OFF</sub>	Power Down Leakage Current	$V_1$ or $V_0 = 5.5V$		0	_		±2	μА		
Icc	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> = 0		1.65V to 5.5V	_	_	4	μА		
ΔI <sub>CC</sub>	Additional Supply Current	Input at V <sub>CC</sub> –0.6V		2.3V to 5.5V	_	_	500	μA		
Cı	Input Capacitance	V <sub>I</sub> = 5.5V to GND		3.3V	_	5.0	_	pF		

# **Package Characteristics**

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Unit
θја	Thermal Resistance Junction-to-Ambient	SOT353	Note 10	-	371		°C/W
θις	Thermal Resistance Junction-to-Case	SOT353	Note 10	_	143	_	°C/W

Note: 10. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



# **Switching Characteristics**

Figure 1 Typical Values at  $T_A$  = +25°C and nominal voltages 1.8V, 2.5V, 2.7V, 3.3V, and 5.0V.

Parameter	From	То	V	T <sub>A</sub> = -4	40°C to 12	5°C	Unit
Farameter	Input	Output	V <sub>CC</sub>	Min	Тур	Max	Oilit
			1.8V ± 0.15V	1.0	4.1	14.0	
			2.5V ± 0.2V	0.7	2.8	8.5	
$t_{PD}$	Α	Y	2.7V	0.7	3.2	8.5	ns
			3.3V ± 0.3V	0.7	3.0	7.0	
			5.0V ± 0.5V	0.7	2.2	6.5	

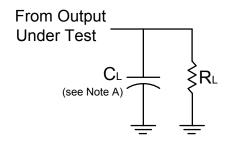
# **Operating Characteristics**

T<sub>A</sub> = +25°C

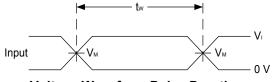
Parameter		Test Conditions	V <sub>CC</sub> = 1.8V Typ.	V <sub>CC</sub> = 2.5V Typ.	V <sub>CC</sub> = 3.3V Typ.	V <sub>CC</sub> = 5V Typ.	Unit
$C_{pd}$	Power Dissipation Capacitance	f = 10 MHz	14	15	15	16	pF



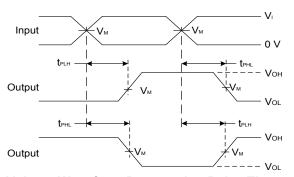
### **Parameter Measurement Information**



V	Inputs		V	0.	D.	
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL	$R_L$	
1.8V±0.15V	Vcc	≤2ns	V <sub>CC</sub> /2	30pF	1kΩ	
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	500Ω	
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω	
5V±0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	50pF	500Ω	







**Voltage Waveform Propagation Delay Times** Inverting and Non Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

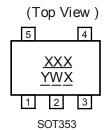
Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10MHz.
   C. Inputs are measured separately one transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>PD</sub>.



# **Marking Information**

SOT353



XXX : Identification Code
Y : Year 0~9
W : Week: A~Z 1~26 week
a~z 27~52 week
z represents week 52 and 53

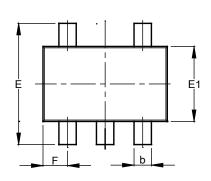
: A~ Z: Internal Code

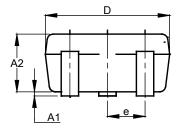
Part Number	Package	Identification Code	
74LVC1G17QSE-7	SOT353	URQ	

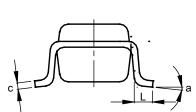


### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.





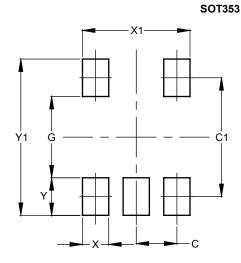


**SOT353** 

	SC	T353	
Dim	Min	Max	Тур
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
C	0.10	0.22	0.11
D	1.80	2.20	2.15
Е	2.00	2.20	2.10
E1	1.15	1.35	1.30
е	(	).650 B	SC
F	0.40	0.45	0.425
L	0.25	0.40	0.30
а	0°	8°	
All	Dimen	sions	in mm

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value
	(in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Υ	0.600
Y1	2 500



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